

IXFH24N80P Datasheet



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DiGi Electronics Part Number IXFH24N80P-DG

Manufacturer IXYS

Manufacturer Product Number IXFH24N80P

Description MOSFET N-CH 800V 24A TO247AD

Detailed Description N-Channel 800 V 24A (Tc) 650W (Tc) Through Hole

TO-247AD (IXFH)



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DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
IXFH24N80P	IXYS
Series:	Product Status:
HiPerFET™, Polar	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
800 V	24A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	400mOhm @ 12A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
5V @ 4mA	105 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	7200 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	650W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-247AD (IXFH)	TO-247-3
Base Product Number:	
IXFH24	

Environmental & Export classification

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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